NSN 5961-01-033-8776

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Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-033-8776 **Overall Length:** 0.125 inches **Overall Diameter:** Between 0.083 inches and 0.093 inches **Internal Configuration:** Junction contact **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 100.00 microamperes source cutoff current and 100.00 microamperes source cutoff current blank **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector absolute **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 00724-20-00688 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 flange and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: